
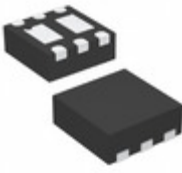
	<h2>SIA811DJ-T1-E3</h2>
	<p>Hersteller-Teilenummer: SIA811DJ-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 4.5A SC70-6</p> <p>Datenblätter:  SIA811DJ-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 16685 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA811DJ-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 4.5A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	16685 pcs Stock
Serie	LITTLE FOOT®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Verlustleistung (max)	1.9W (Ta), 6.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	94 mOhm @ 2.8A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	355pF @ 10V
Verpackung	Tape & Reel (TR)


















































SIA811DJ-T1-E3 ist neu im Original, Suche SIA811DJ-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA811DJ-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA811DJ-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA811ADJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.5A PPAK SC70-6</p>	 <p>SIA811DJ-T1 VISHAY SIA811DJ-T1 VISHAY</p>	 <p>SIA811ADJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 4.5A PPAK SC70-6</p>	 <p>SIA810DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 4.5A SC70-6</p>
 <p>SIA811DJ-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.5A SC70-6</p>	 <p>SIA813DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.5A SC70-6</p>	 <p>SIA813DJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 4.5A SC70-6</p>	 <p>SIA811DJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 4.5A SC70-6</p>

heiße Teile

Mehr

 SIA450DJ-T1-GE3	 SIA450DJ-T1-GE3	 SIA4528-100K	 SIA4528-330K	 SIA4528-470K
 SIA453EDJ-T1-GE3	 SIA453EDJ-T1-GE3	 SIA456DJ-T1-GE3	 SIA456DJ-T1-GE3	 SIA483DJ-T1-GE3
 SIA483DJ-T1-GE3	 SIA513DJ-T1-E3	 SIA517DJ-T1-GE3	 SIA517DJ-T1-GE3	 SIA517DJ-T4-GE3
 SIA519EDJ-T1-GE3	 SIA519EDJ-T1-GE3	 SIA533EDJ-T1-GE3	 SIA533EDJ-T1-GE3	 SIA778DJ-T1-GE3
 SIA778DJ-T1-GE3	 SIA811ADJ-T1-GE3	 SIA811ADJ-T1-GE3	 SIA811DJ-T1	 SIA811DJ-T1-E3
 SIA811DJ-T1-GE3	 SIA811DJ-T1-GE3	 SIA813DJ-T1-GE3	 SIA813DJ-T1-GE3	 SIA814DJ-T1-GE3
 SIA814DJ-T1-GE3	 SIA906EDJ-T1-GE3	 SIA906EDJ-T1-GE3	 SIA906EDJ-T4-GE3	 SIA907EDJT
 SIA907EDJT-T1-GE3	 SIA907EDJT-T1-GE3	 SIA907EDJT-T4-GE3	 SIA910EDJ-T1-GE3	 SIA910EDJ-T1-GE3
 SIA911ADJ-T1-GE3	 SIA911ADJ-T1-GE3	 SIA911ADJ-T5-GE3	 SIA911DJ-T1-E3	 SIA911DJ-T1-E3
 SIA911DJ-T1-GE3	 SIA911DJ-T1-GE3	 SIA911DJ-T5-GE3	 SIA911EDJ-T1-GE3	 SIA911EDJ-T1-GE3

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